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# OPA348AIDBVR-MS/OPA348AIDCKR-MS

**Product specification** 





#### **GENERAL DESCRIPTION**

The OPA348AIDBVR-MS/OPA348AIDCKR-MS is a CMOS operational amplifier that uses the proprietary auto-calibration technique to simultaneously provide very low offset voltage,near-zero drift over time and temperature. This miniature, high-precision, low quiescent current amplifiers offer high-impedance inputs that have a common-mode range 200mV beyond the rails, and rai-to-rail output that swings within 50mV of the rails, single or dual supplies as low as  $2.1V(\pm 1.35V)$  and up to  $5.5V(\pm 2.75V)$  can be used. This device is optimized for low voltage, single supply operation.

The OPA348AIDBVR-MS/OPA348AIDCKR-MS offers excellent CMRR without the crossover associated with traditional complementary input stages. This design results in superior performance for driving analog-to-digital converters (ADC) without degradation of differential linearity.

The OPA348AIDBVR-MS/OPA348AIDCKR-MS is available in the 5-pin SOT-23-5 and SC70-5 packages,and specified for operation from -40°C to 125°C.

#### **FEATURES**

- VDD range:2.1V to 5.5V
- Low Ofset Voltage:0.5mV (Typical)
- Low Drift:0.65µV/C(Typical)
- Low Noise
- Quiescent Current:28µA
- Rail to Rail Input/Output
- MicroSize Packages:SC70-5 and SOT23-5

### Applications

- Transducers
- Temperature Measurement
- Electronic Scales
- Medical instrumentation
- Handheld Test Equipment

#### **Reference News**

PACKAGE OUTLINE		PIN CON	Marking		
	-Jan	OUT 1 5 V+ V- 2 + - +IN 3 4 -IN	+IN 1 V- 2 -IN 3 4 OUT	A 48	●S48
SOT-23-5	SC70-5	SOT-23-5	SC70-5	SOT-23-5	SC70-5

#### **PIN DESCRIPTION**

NAME	PIN				
	DBV (SOT-23)	DCK (SC70)	I/O	DESCRIPTION	
–IN	4	3	I	Negative (inverting) input	
+IN	3	1	1	Positive (noninverting) input	
NC		_	_	No internal connection (can be left floating)	
OUT	1	4	0	Output	
V–	2	2	_	Negative (lowest) power supply	
V+	5	5	_	Positive (highest) power supply	



### SIMPLIFIED SCHEMATIC

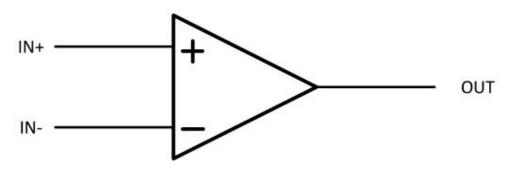


Figure 1.Simpliied Schematic

## ABSOLUTE MAXIMUM RATINGS

Thermal Resistance 0 Jc	130°C/W
Supply Voltage2	.1to 5.5V
Signal Input Terminals Voltage0.1 to (V+	)+0.1V
Operating Junction Temperature	. <b>150°</b> ℃
Operating Temperature Range40°C t	o 125°C
Storage Temperature65°°C to	o 150℃

### **REEL SPECIFICATION**

P/N	PKG	QTY
OPA348AIDBVR-MS	SOT-23-5	3000
OPA348AIDCKR-MS	SC70-5	3000



### **ELECTRICAL CHARACTERISTICS**

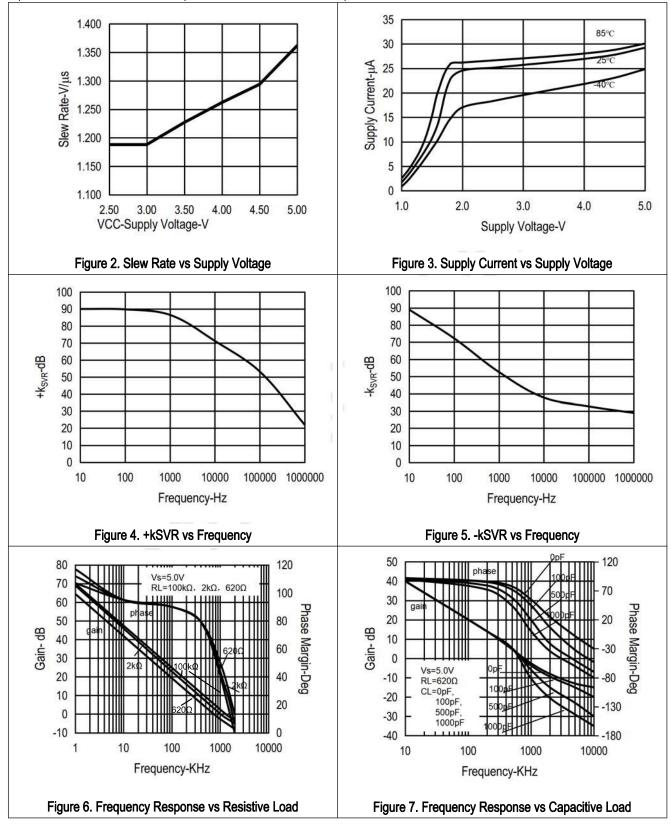
(At TA=25° C, RL=10k connected to Vs/2, and Vour=Vs/2, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
Input Offset Voltage	Vs=±2.5V	-3	0.5	3	mV
nput Offset Voltage Drift	TA=-40°℃ to 125°℃		0.65		<b>µV/</b> ℃
Power Supply Rejection Ratio	Vs =2.1V to 5.5V TA=-40℃ to 125℃	80	90		dB
Input Bias Curren	<b>TA=25</b> ℃		2.0		рА
Input Offset Current			1.0		рА
Common-mode Voltage Range		(V-)-0.1		(V+)+0.1	V
Common-mode Rejection Ratio	V-)-0.1 <vcm<(v+)+0.1 TA=-40℃ to 125℃</vcm<(v+)+0.1 	80	95		dB
Open Loop Voltage Gain	(V-)+100mV <vo<(v+)-10 0mV, RL=10k TA=-40°℃ to 125℃</vo<(v+)-10 	80	100		dB
Gain-bandwidth product	CL=120pF		1.5		MHz
Slew Rate	G=+1		1.2		V/µs
Specified Voltage Range		1.8		5.5	V
Quiescent Current			28	40	μA
Operating Temperature Range		-40		125	°C
Storage Temperature Range		-65		150	°C



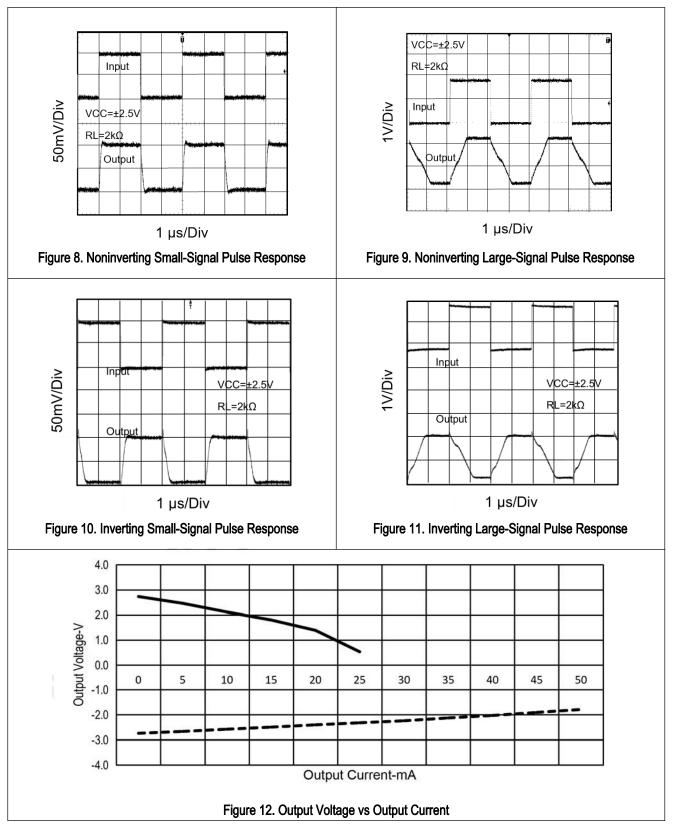
# **TYPICAL PERFORMANCE CHARACTERISTICS**

(At T<sub>A</sub> = 25°C,V<sub>S</sub>=5V, C<sub>L</sub>=20pF, unless otherwise noted.)





# **TYPICAL PERFORMANCE CHARACTERISTICS**





# FUNCTIONAL DESCRIPTION

#### Operating Voltage

The OPA348AIDBVR-MS/OPA348AIDCKR-MS devices are fully specified and ensured for operation from 2.1V to 5.5 V.In addition, many specifications apply from  $-40^{\circ}$ C to  $125^{\circ}$ C. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics graphs.

#### **Unity-Gain Bandwidth**

The unity-gain bandwidth is the frequency up to which an amplifier with a unity gain may be operated without greatly distorting the signal.The OPA348AIDBVR-MS/OPA348AIDCKR-MS device has a 1.5-MHz unity-gain bandwidth.

#### **APPLICATIONS INFORMATION**

The OPA348AIDBVR-MS/OPA348AIDCKR-MS is a unity-gain stable,precision operational amplifier with very low offset voltage drift; these devices are also free from output phase reversal.Applications with noisy or high-impedance power supplies require decoupling capacitors close to the device power-supply pins.In most cases, 0.1µF capacitors are adequate.

#### **Typical Application**

Figure 13 shows a simple circuit to convert a single-ended input into differential output.The OPA348AIDBVR-MS/OPA348AIDCKR-MS could be used to build this circuit.The circuit is composed of two amplifiers.One amplifier acts as a buffer and creates a voltage,VouT+.The second amplifier inverts the input and adds a reference voltage to generate Vour-.Both Vour+ and Vour-range from 0.5 to 2 V.The diference, VDIFF, is the difference between Vour+and VouT-.

#### **Slew Rate**

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input.The OPA348AIDBVR-MS/OPA348AIDCKR-MS devices have a1 .2-V/ $\mu$  s slew rate.The OPA348AIDBVR-MS/OPA348AIDCKR-MS is characterized toperform with this technique;the recommended resistor value is approximately 20 k.

#### **Device Functional Modes**

The OPA348AIDBVR-MS/OPA348AIDCKR-MS device has a single functional mode. The device is powered on as long as the power supply voltage is between 2.1V(±1.35V)and 5.5V(±2.75V)

#### **Detailed Design Procedure**

Linearity over the input range is key for good dc accuracy. The common mode input range and the output swing limitations determine the linearity. In general, an amplifier with rail-to-rail input and output swing is required. Bandwidth is a key concern for this design. Because OPA348AIDBVR-MS/OPA348AIDCKR-MS has a bandwidth of 1MHz, this circuit will only be able to process signals with frequencies of less than 1 MHz.

Because the transfer function of Vour-is heavily reliant on resistors(R1,R2,R3,and R4),use resistors with low tolerances to maximize performance and minimize error.This design used resistors with resistance values of 36 k with tolerances measured to be within 2%.If the noise of the system is a key parameter,the user can select smaller resistance values (6 k or lower)to keep the overall system noise low.This ensures that the noise from the resistors is lower than the amplifier noise.



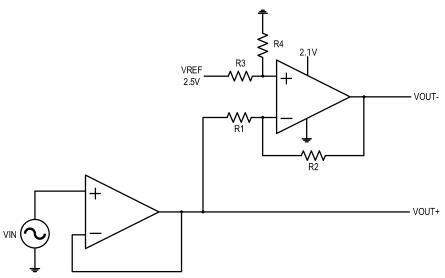
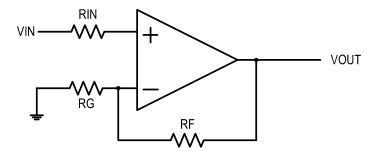


Figure 13. Schematic for Single-Ended Input to Differential Output Conversion

# LAYOUT

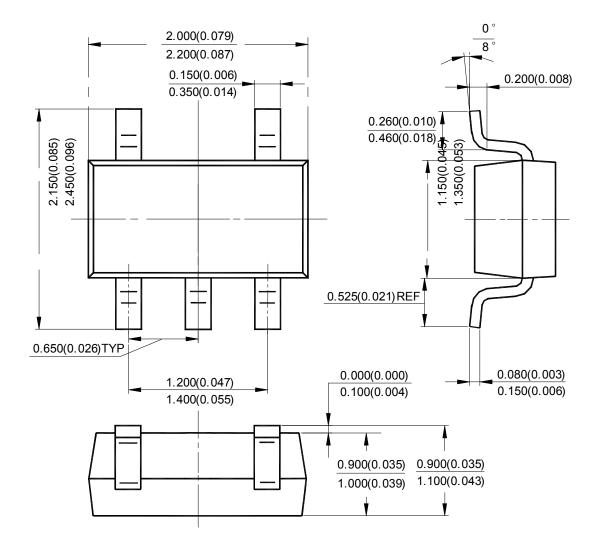
Use good PCB layout practices for best operational performance of the device, including:

- Keep the length of input traces as short as possible.
- Run the input traces as far away from the supply lines as possible to reduce parasitic coupling.
- Place components close to device and to each other to reduce parasitic capacitance and parasitic errors.
- Use low-ESR, ceramic bypass capacitors to reduce the coupled noise by providing low impedance power sources local to the analog circuitry.
- Grounding for analog and digital portions of circuitry separately to suppresse the noise.





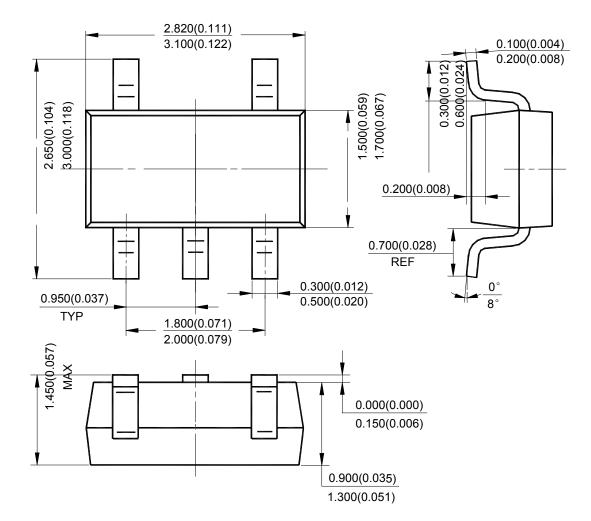
#### Package Outline Dimensions (All dimensions in mm(inch).)



SC-70-5



#### Package Outline Dimensions (Cont. All dimensions in mm(inch).)



SOT-23-5

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